



3.3V, Hot Insertion, 8-Bit, 2-Port NanoSwitch™

Features

- → Near-Zero propagation delay
- → 5-ohm switches connect inputs to outputs
- → Fast Switching Speed: 4.5ns (max.)
- → Ultra-Low Quiescent Power (0.2µA Typical)
 - Ideally suited for notebook applications
- → TTL-compatible control of inputs levels
- → ESD protection (2kV Human Body Model and 200V Machine Model)
- → Packaging (Pb-free & Green):

□ 20-pin SOIC (S)

Block Diagram



Truth Table

| Function | BE | A0-7 |
|------------|----|------|
| Disconnect | Н | Hi-Z |
| Connect | L | B0-7 |

Note:

H = High Voltage Level, L = Low Voltage Level, Hi-Z = High Impedance

Description

The PI3B3245 is a 3.3V 8-bit, 2-port bus switch designed with a low On-Resistance (5-ohm) allowing inputs to be connected directly to outputs. The bus switch creates no additional propagational delay or additional ground bounce noise. The switches are turned ON by the Bus Enable (\overline{BE}) input signal.

Pin Configuration



Pin Description

| Pin Name | Description | |
|-----------------|-------------------------------|--|
| BE | Bus Enable Input (Active LOW) | |
| A0-7 | Bus A | |
| B0-7 | Bus B | |
| GND | Ground | |
| V _{CC} | Power | |





Absolute Maximum Ratings

| Parameter | | Max. | Units |
|--|-----|------|-------|
| Storage Temperature | -65 | 150 | °C |
| Ambient Temperature with Power Applied | | 85 | °C |
| Supply Voltage to Ground Potential | | 4.6 | V |
| DC Input Voltage | | 4.6 | V |
| DC Output Current | | 120 | mA |
| Power Dissipation | - | 0.5 | W |

Stress beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = 3.3$ V $\pm 10\%$)

| Parameters | Description | Test Conditions ⁽¹⁾ | Min | Typ ⁽²⁾ | Max | Units |
|-----------------|-------------------------------------|---|------|---------------------------|------|-------|
| V _{IH} | Input HIGH Voltage | Guaranteed Logic HIGH Level | 2.0 | | | V |
| VIL | Input LOW Voltage | Guaranteed Logic LOW Level | -0.5 | | 0.8 | V |
| I _{IH} | Input HIGH Current | $V_{CC} = Max., V_{IN} = V_{CC}$ | | | ±1 | μΑ |
| I _{IL} | Input LOW Current | V _{CC} = Max., V _{IN} = GND | | | ±1 | μΑ |
| Iozh | High Impedance Output Current | $0 \le A_N, B_N \le V_{CC}$ | | | ±1 | μΑ |
| VIK | Clamp Diode Voltage | V_{CC} = Min., I_{IN} = -18 mA | | | -1.2 | V |
| R _{ON} | Switch On Resistance ⁽³⁾ | $V_{CC} = Min., V_{IN} = 0.0V, I_{ON} = 48mA$ or $64mA$ | | 5 | 8 | Ω |
| | | $V_{CC} = Min, V_{IN} = 2.4V, I_{ON} = 15mA$ | | 10 | 17 | |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 3.3V, $T_A = 25^{\circ}C$ ambient and maximum loading.

3. Measured by the voltage drop between A and B pin at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A,B) pins.

Capacitance $(T_A = 25^{\circ}C, f = 1 \text{ MHz})$

| Parameters ⁽¹⁾ | Description | Test Conditions | Тур | Units |
|---------------------------|-----------------------------|-------------------|------|-------|
| C _{IN} | Input Capacitance | $V_{\rm IN} = 0V$ | 3.0 | pF |
| C _{OFF} | A/B Capacitance, Switch Off | $V_{\rm IN} = 0V$ | 8.0 | pF |
| C _{ON} | A/B Capacitance, Switch On | $V_{\rm IN} = 0V$ | 16.0 | pF |

Notes:

1. This parameter is determined by device characterization but is not production tested.

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Power Supply Characteristics

| Parameters | Description | Test Conditions ⁽¹⁾ | | Min | Typ ⁽²⁾ | Max | Units |
|-----------------|--------------------------------|--------------------------------|-----------------------------------|-----|---------------------------|-----|-------|
| I _{CC} | Quiescent Power Supply Current | V _{CC} = Max. | $V_{IN} = GND \text{ or } V_{CC}$ | | 0.1 | 3.0 | μΑ |
| ΔI_{CC} | Supply Current per Input HIGH | $V_{CC} = Max.$ | $V_{IN} = 3.0 V^{(3)}$ | | | 750 | μA |

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

3. Per TTL driven input (control input only); A and B pins do not contribute to Icc.

Switching Characteristics over Operating Range

| | | | Com. | | |
|--------------------------------------|--|---------------------------------------|------|------|-------|
| Parameters | Description | Test Conditions | Min | Max | Units |
| t _{PLH} t _{PHL} | Propagation Delay ^(1,2) Ax to Bx, Bx to Ax | | | 0.25 | |
| t _{PZH} t _{PZL} | Bus Enable Time BE to Ax or Bx | $CL = 50 \text{ pF}$ $RL = 500\Omega$ | 1.0 | 4.0 | ns |
| t _{PHZ} t _{PLZ} | $\frac{Bus}{BE} \text{ to } Ax \text{ or } Bx$ | | 1.0 | 4.5 | |

Notes:

1. This parameter is guaranteed but not tested on Propagation Delays.

2. The bus switch contributes no propagational delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

Applications Information

Logic Inputs

The logic control inputs can be driven up to +3.6V regardless of the supply voltage. For example, given a +3.3V supply, A_N may be driven low to 0V and high to 3.6V. Driving B_N Rail-to-Rail[®] minimizes power consumption.

Power-Supply Sequencing and Hot-Plug Information

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V_{CC} and GND before applying signals to input/output or control pins.

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A product Line of Diodes Incorporated

PI3B3245

Packaging Mechanical: 20-Pin SOIC (S)



Note: For latest package info, please check: http://www.pericom.com/support/packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

| Ordering Code | Package Code | Package Type |
|---------------|--------------|---|
| PI3B3245SE | S | 20-pin, 300Mil Wide (SOIC) |
| PI3B3245SEX | S | 20-pin, 300Mil Wide (SOIC), Tape & Reel |

Notes:

- 1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- 2. E = Pb-free and Green
- 3. Adding an X suffix = Tape/Reel





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